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Marco Musiani, Mark E. Orazem, Nadine Pébère, Bernard Tribollet, Vincent Vivier. Constant-Phase-Element Behavior Caused by Coupled Resistivity and Permittivity Distributions in Films. *Journal of The Electrochemical Society*, 2011, 158 (12), pp.C424-C428. 10.1149/2.039112jes. hal-00826261

HAL Id: hal-00826261

<https://hal.sorbonne-universite.fr/hal-00826261v1>

Submitted on 24 Jan 2022

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To link to this article: DOI: 10.1149/2.039112jes
URL : <http://dx.doi.org/10.1149/2.039112jes>

To cite this version:

Musiani, M. and Orazem, Mark E. and Pébère, Nadine and Tribollet, Bernard and Vivier, Vincent *Constant-Phase-Element Behavior Caused by Coupled Resistivity and Permittivity Distributions in Films*. (2011) Journal of The Electrochemical Society (JES), vol. 158 (n° 12). pp. C424-C428. ISSN 0013-4651

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Constant-Phase-Element Behavior Caused by Coupled Resistivity and Permittivity Distributions in Films

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A recent proposed model showed that the impedance of a film with a uniform permittivity and a resistivity that varies along its thickness according to a power-law is in the form of a constant phase element (CPE). This model is further considered in order to assess the effect of non-uniform permittivity profiles. It is shown that a power-law permittivity profile is also compatible with a CPE behavior when resistivity and permittivity vary in opposite ways along the film thickness. This work shows that, for important classes of materials which show CPE behavior, relaxation of the assumption of a uniform permittivity does not alter the conclusions developed in the earlier work, and the formula relating film properties to CPE parameters is shown to apply.

[DOI: 10.1149/2.039112jes]

In a recent paper, Hirschorn et al.¹ showed that the impedance of a film, with a uniform permittivity (ϵ) and a resistivity (ρ) that varies along its thickness (δ) according to a power-law, is in the form of a constant phase element (CPE) in a well-defined frequency range between two characteristic frequencies (defined below). The existence of marked variations in the impedance of organic coatings along their thickness had been experimentally shown some years ago by Kittel et al.² These workers pointed out that it would be desirable "to use a mathematical model integrating a properties gradient over the thickness of the coatings,"³ but did not propose any specific resistivity or permittivity profiles. In Ref. 1 the film resistivity was written as:

$$\frac{\rho(\xi)}{\rho(\delta)} = \left[\frac{\rho(\delta)}{\rho(0)} + \left(1 - \frac{\rho(\delta)}{\rho(0)} \right) \xi^\gamma \right]^{-1} \quad [1]$$

where $\rho(0)$ and $\rho(\delta)$ are the boundary values of resistivity at the interfaces, $\xi = x/\delta$ (x is the distance along the film thickness) and γ is a parameter indicating how sharply the resistivity varies. Formulas for the calculation of $\rho(0)$, $\rho(\delta)$ and γ from the experimental data were proposed, which however, to be applied, required the knowledge of both δ and ϵ . In many cases, the film thickness may be measured by microscopic or spectroscopic techniques, and a fairly accurate permittivity value may be estimated when the chemical composition of the film is known. In the same paper,¹ it was pointed out that, if the resistivity distribution results from an inhomogeneous layer composition, then a permittivity profile may also be expected. Although the variations of ϵ should be much smaller than those of ρ , they may influence the shape of the impedance diagrams.

The present communication addresses the influence of a non-uniform permittivity on the impedance of a film with a power-law resistivity profile. The discussion is mainly focused on the case of a coating that uptakes an electrolytic solution in an inhomogeneous way, more strongly in its outer part, in contact with the electrolyte, than in its inner part, in contact with the metal, as observed by Kittel et al.³ for epoxy vinyl primer coatings with TiO_2 and ZnSO_4 as additives. Such a situation is compatible with the resistivity profile described by equation 1 with $\rho(0) > \rho(\delta)$, assuming that $x = 0$ and $x = \delta$ denote the metal/coating and coating/electrolyte interfaces, respectively. As the electrolytic solution uptake is expected to cause an increase in the coating permittivity,⁴⁻⁶ one should expect a permittivity profile with $\epsilon(0) < \epsilon(\delta)$.

Results and Discussion

For the present analysis, the permittivity was assumed to vary along the film thickness, in a manner similar to that of the resistivity, according to a power-law, i.e.,

$$\frac{\epsilon(\xi)}{\epsilon(\delta)} = \left[\frac{\epsilon(\delta)}{\epsilon(0)} + \left(1 - \frac{\epsilon(\delta)}{\epsilon(0)} \right) \xi^{\gamma'} \right]^{-1} \quad [2]$$

In equation 2, γ' is used as power-law exponent to indicate that, in principle, it may not coincide with γ . However, if the cause of the resistivity and permittivity profiles is the same, e.g., a composition profile, it is logical to assume that ρ and ϵ should vary on the same scale length and therefore $\gamma = \gamma'$. This case is considered, at first, in greater detail; the effect of assuming $\gamma \neq \gamma'$ is discussed later.

A set of resistivity and permittivity profiles calculated according to equations 1 and 2, respectively, are presented in Figure 1 for various values of the power-law exponent $\gamma = \gamma'$. The resistivity values at $\xi = 0$ and $\xi = 1$ are given by $\rho(0) = 10^{10} \Omega \text{ cm}$ and $\rho(\delta) = 10^5 \Omega \text{ cm}$ respectively. The logarithmic scale shown in Figure 1a illustrates the power-law nature of the distribution; whereas, the linear presentation of scaled resistivity in Figure 1b shows that the resistivity becomes very small with respect to the maximum resistivity, $\rho(0)$, over a significant portion of the film.

A permittivity $\epsilon(0) = 3$ was assumed at the metal/coating interface because such a value is within the expected range for dry polymeric materials. A permittivity $\epsilon(\delta) = 30$ was assumed to apply for the coating/electrolyte interface. This value, 10 times larger than $\epsilon(0)$, would correspond to a massive electrolyte uptake⁴⁻⁶ (for example, to ca 50% volume fraction of electrolyte according to Brasher and Kingsbury⁴ and to at least 28% volume fraction according to other effective medium formulas⁶). The resulting permittivity, presented in a linear scale in Figure 1c, shows that the permittivity increases markedly only in the outer part of the film where the resistivity is very small.

The film impedance, given by

$$Z_f(\omega) = \delta \int_0^1 \frac{1}{\rho(\xi)^{-1} + j\omega\epsilon(\xi)\epsilon_0} d\xi \quad [3]$$

was numerically calculated over a wide frequency range, markedly larger than the one usually employed in experiments. The large frequency range is employed here to explore fully the dielectric response of the film. At the highest frequencies reported in the present work, one may expect to observe other high-frequency phenomena, not included in the model, such as dielectric relaxation of the electrolyte. The frequency dependencies of the real part (a) imaginary part (b), and

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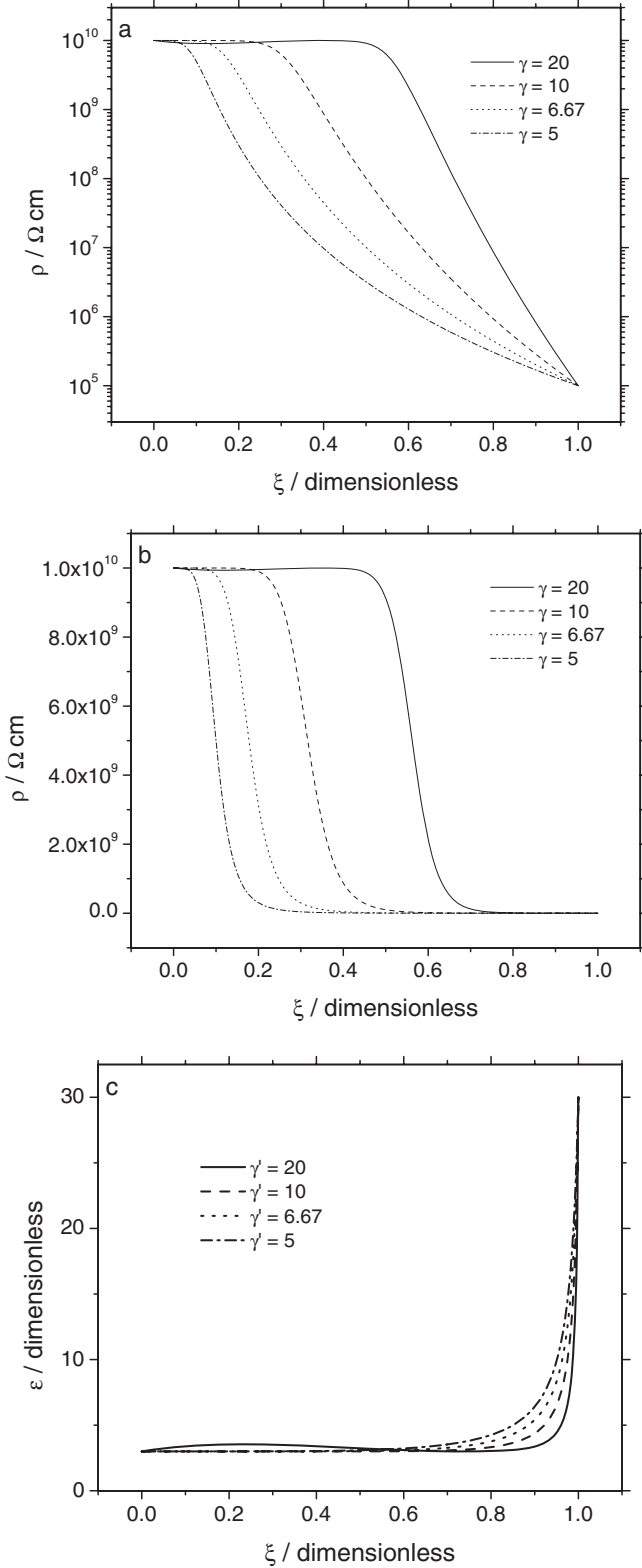


Figure 1. Resistivity and permittivity profiles calculated according to equations 1 and 2, respectively, with $\rho(0) = 10^{10} \Omega \text{ cm}$, $\rho(\delta) = 10^5 \Omega \text{ cm}$, $\epsilon(0) = 3$, $\epsilon(\delta) = 30$, $\delta = 2 \cdot 10^{-4} \text{ cm}$, and $\gamma = \gamma'$ as a parameter: a) resistivity on logarithmic scale; b) resistivity on linear scale; and c) permittivity on linear scale.

derivative $d \log(-Z_j)/d \log(f)$ (c) are presented in Figure 2 for the values of $\rho(0)$, $\rho(\delta)$, γ and γ' corresponding to the resistivity and permittivity profiles shown in Figure 1. These plots clearly show a CPE behavior over the range between 100 Hz and 1 MHz, highlighted by the constant $d \log(-Z_j)/d \log(f)$ value which corresponds to the CPE exponent α ,⁷ linked to the power-law exponent γ by the relationship¹

$$\alpha = (\gamma - 1)/\gamma \quad [4]$$

Thus, a non-uniform permittivity profile is compatible with a CPE behavior. However, it is important to note that, in Figure 1, the permittivity varies sharply only in a ξ range where the resistivity is very small, i.e. in a part of the film that contributes to the overall impedance in an almost negligible way.

The fact that a CPE behavior is still observed when ϵ is not uniform does not necessarily mean that the formulas proposed in Ref. 1 can still be used to calculate $\rho(0)$ and $\rho(\delta)$. To clarify this point, the impedance plots shown in Figure 3 were calculated. A film with a uniform permittivity ($\epsilon(0) = \epsilon(\delta) = 3$) was compared to films with inhomogeneous permittivity; permittivity variations between $\epsilon(0) = 3$ and $\epsilon(\delta) = 10$ (roughly corresponding to 25% water uptake⁴ at the coating/electrolyte interface) and between $\epsilon(0) = 3$ and $\epsilon(\delta) = 30$ were considered. The frequency dependence of the imaginary part of the impedance is shown in Figure 3a. The real part is not shown, as it does not convey additional information.

Clearly, minor differences are seen only in the very high frequency range, where the film behaves as an ideal capacitor.¹ Both the frequency range over which CPE behavior is observed and the low-frequency range are unaffected by the permittivity profile. In particular, the characteristic frequency at which the imaginary part goes through a maximum f_0 , given by

$$f_0 = (2\pi\rho(0)\epsilon(0)\epsilon_0)^{-1} \quad [5]$$

does not depend on $\epsilon(\delta)$. Thus, the experimental value of f_0 can still be used for the calculation of $\rho(0)$, provided the permittivity of the dry coating material is used as $\epsilon(0)$. The values of $d \log(-Z_j)/d \log(f)$ presented in Figure 3b, for the most significant frequency ranges, shows that $\epsilon(\delta)$ has almost no influence on the CPE exponent α . The minor differences among the plots would not be significant in experiments. The frequency dependence of the CPE parameter Q , calculated as⁷

$$Q = \sin\left(\frac{\alpha\pi}{2}\right) \frac{-1}{Z_j(2\pi f)^\alpha} \quad [6]$$

is presented in Figure 3c. Clearly, although the range over which Q is constant is somewhat smaller when $\epsilon(\delta)$ is larger, the Q value is unaffected by the permittivity profile. Thus, given that both α and Q are insensitive to the permittivity profile, $\rho(\delta)$ can still be calculated as¹

$$\rho(\delta) = [\epsilon(0)\epsilon_0]^\alpha / (1-\alpha) [Qg\delta]^{1/(\alpha-1)} \quad [7]$$

using for $\epsilon(0)$ the permittivity of the dry coating material. In equation 7, g is a function of α , with a value close to 1, and is given by $g = 1 + 2.88(\alpha - 1)^{2.375}$.¹ Therefore, if the film resistivity and permittivity are given by equations 1 and 2, respectively, the quantities that define the resistivity profile, i.e. γ , $\rho(0)$ and $\rho(\delta)$ may be calculated using equations 4, 5, and 7 respectively, with the permittivity of the dry coating material given as $\epsilon(0)$.

In Ref. 1, $\rho(\delta)$ was also expressed as $\rho(\delta) = (2\pi f_\delta \epsilon \epsilon_0)^{-1}$, where f_δ is the characteristic frequency marking the transition between the CPE and the capacitive behavior. Such a formula cannot be directly used for the calculation of $\rho(\delta)$ because f_δ depends on $\epsilon(\delta)$. In addition, f_δ is

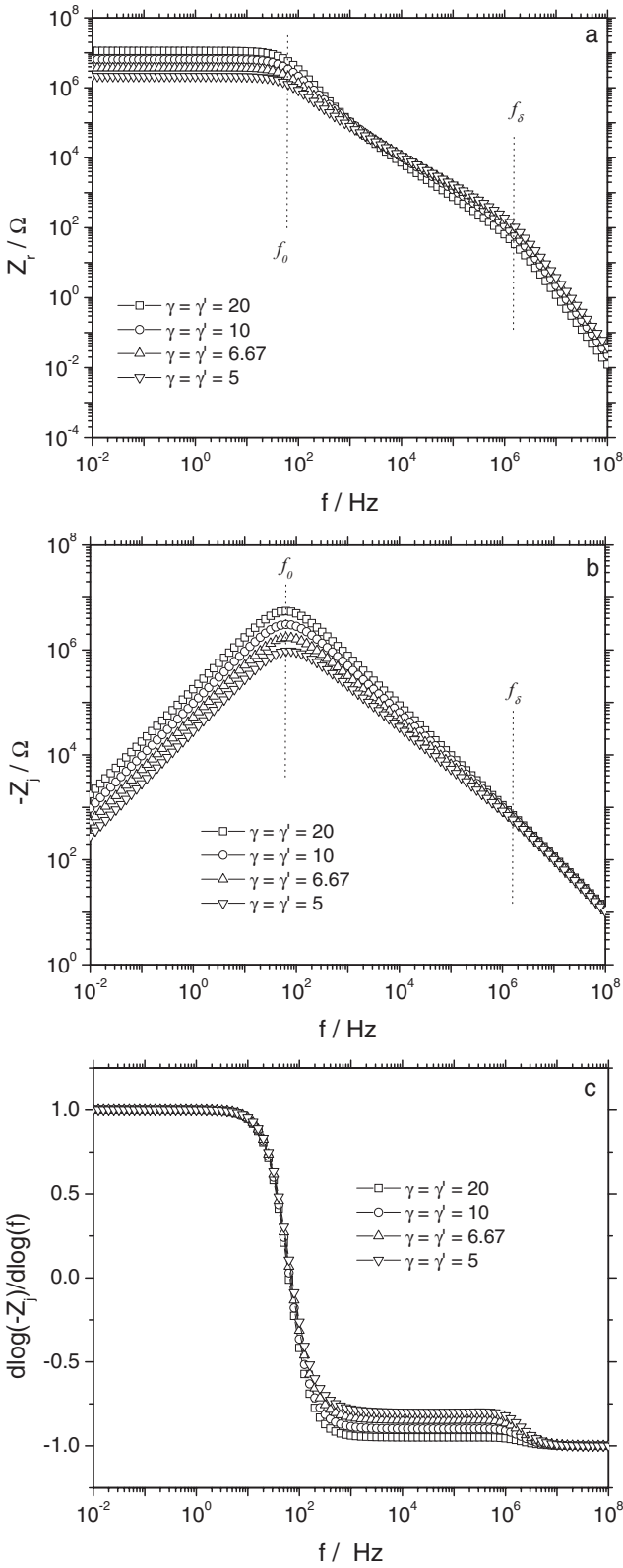


Figure 2. Impedance plots calculated according to equation 3 for resistivity and permittivity profiles given by equations 1 and 2, respectively, with $\rho(0) = 10^{10} \Omega \text{ cm}$, $\rho(\delta) = 10^5 \Omega \text{ cm}$, $\varepsilon(0) = 3$, $\varepsilon(\delta) = 30$, $\delta = 2 \cdot 10^{-4} \text{ cm}$, and $\gamma = \gamma'$ as a parameter: a) real part of the impedance; (b) imaginary part of the impedance; and c) $d \log(-Z_j) / d \log(f)$ corresponding to the CPE exponent α .

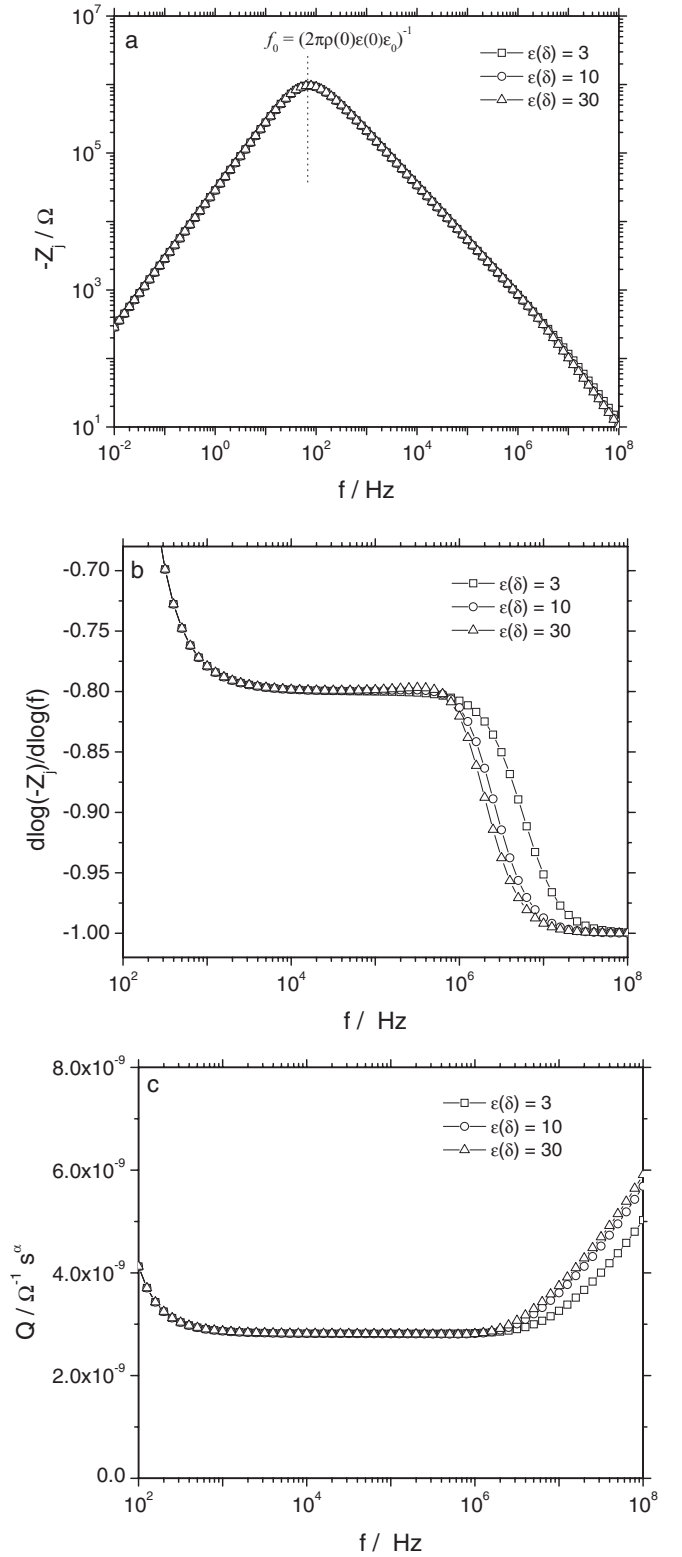


Figure 3. Impedance plots calculated according to equation 3 for resistivity and permittivity profiles given by equations 1 and 2, respectively, with $\rho(0) = 10^{10} \Omega \text{ cm}$, $\rho(\delta) = 10^5 \Omega \text{ cm}$, $\varepsilon(0) = 3$, $\gamma = \gamma' = 5$, $\delta = 2 \cdot 10^{-4} \text{ cm}$, and $\varepsilon(\delta)$ as a parameter: a) imaginary part of the impedance; b) $d \log(-Z_j) / d \log(f)$ corresponding to the CPE exponent α ; and c) CPE parameter Q .

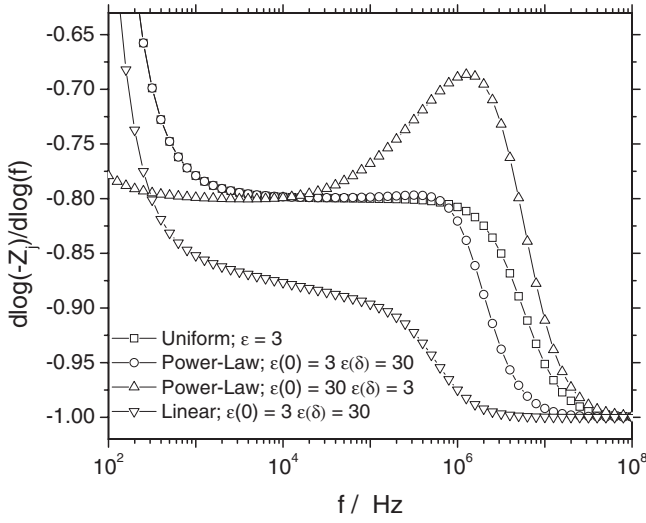


Figure 4. Frequency dependence of the slope $d \log(-Z_j)/d \log(f)$ corresponding to the CPE exponent α , calculated according to equation 3, for a film with a power-law resistivity profile ($\rho(0) = 10^{10} \Omega \text{ cm}$, $\rho(\delta) = 10^5 \Omega \text{ cm}$, $\gamma = \gamma' = 5$, $\delta = 2 \cdot 10^{-4} \text{ cm}$) and for different permittivity profiles as indicated on the figure.

often higher than the upper frequency limit used in the experiments,^{8,9} and, for such cases, its use for the calculation of $\rho(\delta)$ is precluded.

Impedance values were calculated for other permittivity profiles in order to assess which permittivity profiles were compatible with the observation of a CPE behavior, when coupled with a power-law resistivity. In Figure 4, values for $d \log(-Z_j)/d \log(f)$ are presented as a function of frequency for four different cases: (i) uniform permittivity; (ii) power-law permittivity profile given by equation 2 with $\gamma = \gamma'$ and $\varepsilon(0) < \varepsilon(\delta)$; (iii) power-law permittivity profile given by equation 2 with $\gamma = \gamma'$ and $\varepsilon(0) > \varepsilon(\delta)$; and (iv) linear permittivity profile, with $\varepsilon(0) < \varepsilon(\delta)$, given by

$$\varepsilon(x) = \varepsilon(0) - [\varepsilon(0) - \varepsilon(\delta)]\xi \quad [8]$$

As already shown above, distributions (i) and (ii) lead to a CPE behavior, but distributions (iii) and (iv) do not, most probably because, in both cases, the film permittivity changes significantly with ξ in its inner and more resistive part.

Additional simulations were performed with permittivity values following distribution (ii) but with $\varepsilon(\delta) = 300$. Such large values of $\varepsilon(\delta)$ are consistent with dielectric constant values reported for some oxides by Shannon.¹⁰ Even for these more extreme changes in permittivity, the impedance was unaffected by the permittivity distribution, and equation 7 provided an accurate relationship between CPE parameters and film properties. Other simulations were performed which showed that even a staircase distribution of permittivity will show CPE behavior so long as the increase in permittivity takes place in regions where the resistivity is small.

Figure 5a shows permittivity profiles calculated for various γ' values. As γ' becomes smaller, the permittivity profile becomes smoother and the film depth over which a non-negligible ε variation occurs extends to lower ξ values. Figure 5b shows the frequency dependence of the slope $d \log(-Z_j)/d \log(f)$, corresponding to the CPE exponent α , calculated by assuming a constant value of $\gamma = 10$, i.e. a fixed ρ profile (dashed curves in Figures 1a and 1b), and different γ' values. Clearly, as the difference between γ and γ' becomes larger the $d \log(-Z_j)/d \log(f)$ vs. frequency plots diverge from a pure CPE behavior and α becomes frequency dependent. As mentioned above, a significant variation of ε with ξ in the most resistive part of the film appears not to be compatible with a CPE. Of course, the deviation from a CPE behavior would be less evident for differences between $\varepsilon(0)$ and $\varepsilon(\delta)$ lower than those, quite large, considered in Figure 5.

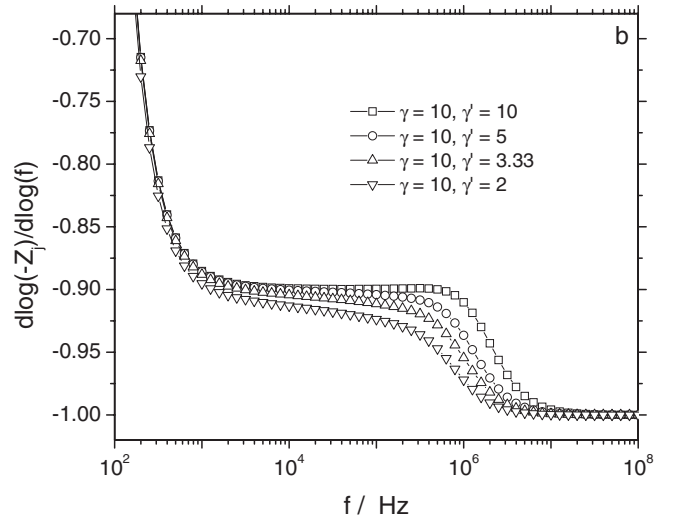
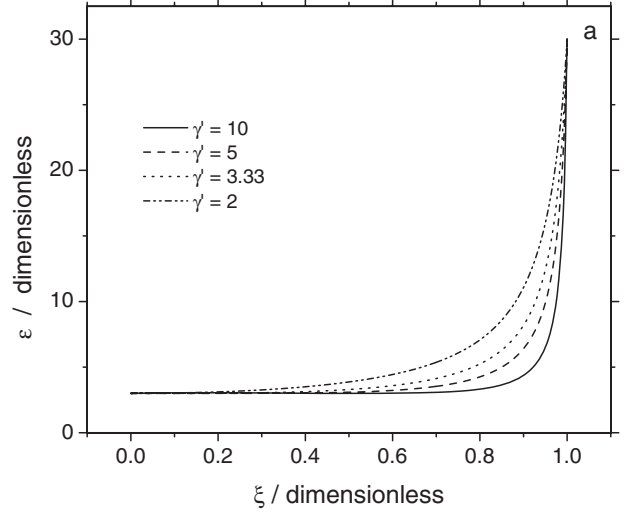


Figure 5. Permittivity profiles (a) and $d \log(-Z_j)/d \log(f)$ vs. frequency plots (b) calculated according to equations 2 and 3 respectively, with $\rho(0) = 10^{10} \Omega \text{ cm}$, $\rho(\delta) = 10^5 \Omega \text{ cm}$, $\varepsilon(0) = 3$, $\varepsilon(\delta) = 30$, $\delta = 2 \cdot 10^{-4} \text{ cm}$, and the γ and γ' values indicated on the figures.

In Ref. 1, the power-law resistivity profile was compared to the exponential profile proposed by Young¹¹ and the authors observed that the latter does not yield a CPE behavior, in agreement with Göhr et al.¹² The plots of $d \log(-Z_j)/d \log(f)$ as a function of frequency, shown in Figure 6a, were calculated according to equation 3, assuming a Young-type resistivity profile with a characteristic length λ , and an exponential permittivity profile, with a characteristic length λ/k , i.e.

$$\rho(x) = \rho(0) \exp\left(\frac{-x}{\lambda}\right) \quad [9]$$

and

$$\varepsilon(x) = \varepsilon(0) \exp\left(\frac{-kx}{\lambda}\right) \quad [10]$$

where k is a dimensionless constant relating the two distributions. It may be seen that such a combination of exponential profiles may yield a CPE behavior. In this case, however, both ρ and ε vary with x in the same way, i.e. if $\rho(0) > \rho(\delta)$ then $\varepsilon(0) > \varepsilon(\delta)$, and the CPE behavior is better defined for larger k values, i.e. sharper ε profiles, leading to α values quite far from 1, seldom encountered in experimental results. The associated permittivity distributions given in Figure 6b show that large k values are likely to correspond to unrealistically wide variations

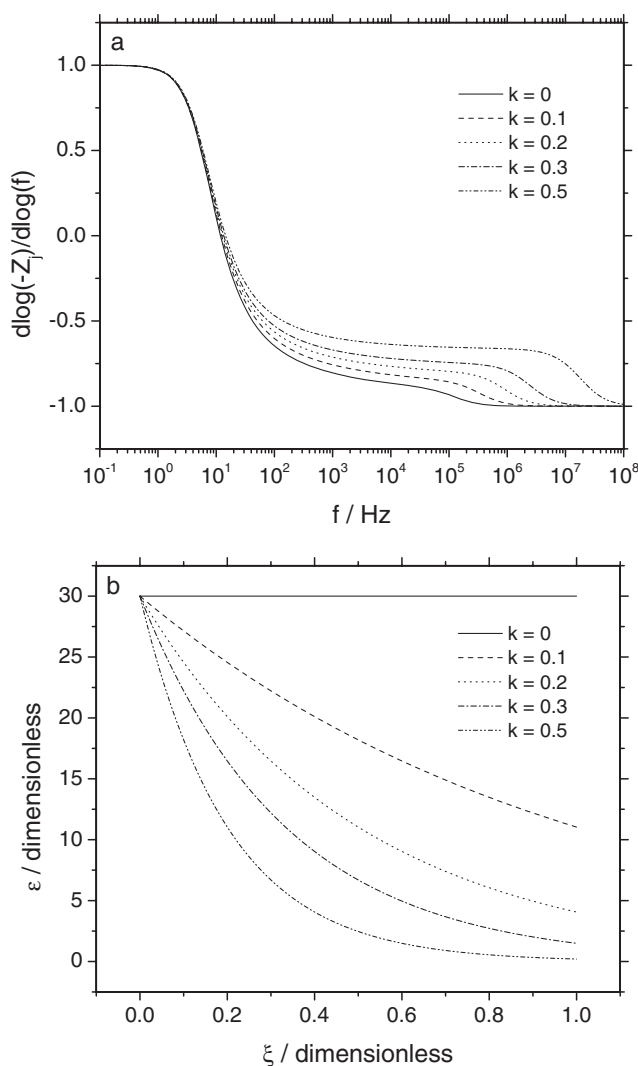


Figure 6. Impedance results calculated according to equation 3 for resistivity and permittivity profiles given by equations 9 and 10, respectively, with $\rho(0) = 10^{10} \Omega \text{ cm}$, $\epsilon(0) = 30$, $\delta = 10^{-6} \text{ cm}$, $\lambda = 10^{-7} \text{ cm}$, and k as a parameter: a) $d \log(-Z_j)/d \log(f)$, corresponding to the CPE exponent α , as a function of frequency; and b) permittivity profiles calculated according to equation 10.

of ϵ across the film. The $\epsilon(\delta)$ values are ca. 11 for $k = 0.1$, 4 for $k = 0.2$, 1.5 for $k = 0.3$ and a physically meaningless 0.2 for $k = 0.5$.

Hirschorn et al.⁸ reported on the use of equation 7, derived under the assumption of a uniform permittivity profile, for a variety of systems, including some for which the assumption of a uniform

permittivity was clearly inappropriate. The present work shows that, so long as the permittivity increases according to equation 2 and the resistivity decreases according to equation 1, with $\gamma = \gamma'$, equation 7 provides a valid relationship between CPE and film parameters. For systems exhibiting CPE behavior, the distribution in permittivity is overwhelmed by the distribution of resistivity. Thus, changes to the film that influence permittivity in the outer region will not influence the impedance response.

Other distributions, such as the Young model, which employs an exponential variation of resistivity, do not yield CPE behavior. Combinations of exponential changes in permittivity and resistivity, in which both increase with position in the same way, will give rise to CPE behavior, but the required profiles are physically unreasonable.

In principle, the concepts reported in the present paper for electrolyte-penetrated organic coatings may apply – at least as a first approximation – to other systems like, for example, passive oxide with inhomogeneous properties along their depth (often described as duplex films consisting of an inner compact, resistive layer and an outer hydrated layer), provided the resistivity and permittivity profiles fulfill the requirements described above.

Conclusions

Numerical calculations have been used to assess the influence of a permittivity profile, coupled to a power-law resistivity profile, on the observation of a CPE behavior in films. It has been shown that a power-law permittivity profile is compatible with a CPE behavior when ρ and ϵ vary with ξ in opposite ways on the same scale length. Such a situation is quite likely to occur in organic coatings which inhomogeneously uptake a conductive water solution. Some other permittivity profiles have been shown to be incompatible with a CPE. A CPE behavior may be observed also for films with exponential profiles of their properties, when ρ and ϵ vary with ξ in the same way, but the corresponding permittivity variations are likely to be too large to be physically acceptable.

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